



Applications Note: SY7701

High Efficiency 500kHz, 25V PWM Controller For WLED backlight application

General Description

SY7701 is a current mode boost controller targeted for WLED backlight application. The device has a wide input voltage range of 3V to 25V. The external compensation provides flexible adjustment of control loop for different applications. The internal low side driver is capable of sourcing 1.5A and sinking 3A current.

Ordering Information

SY7701 □(□□)□
 □ Temperature Code
 □ Package Code
 □ Optional Spec Code

Temperature Range: -40° C to 85° C

Ordering Number	Package type	Note
SY7701DBC	DFN3x3-10	----
SY7701FHC	SOP10	

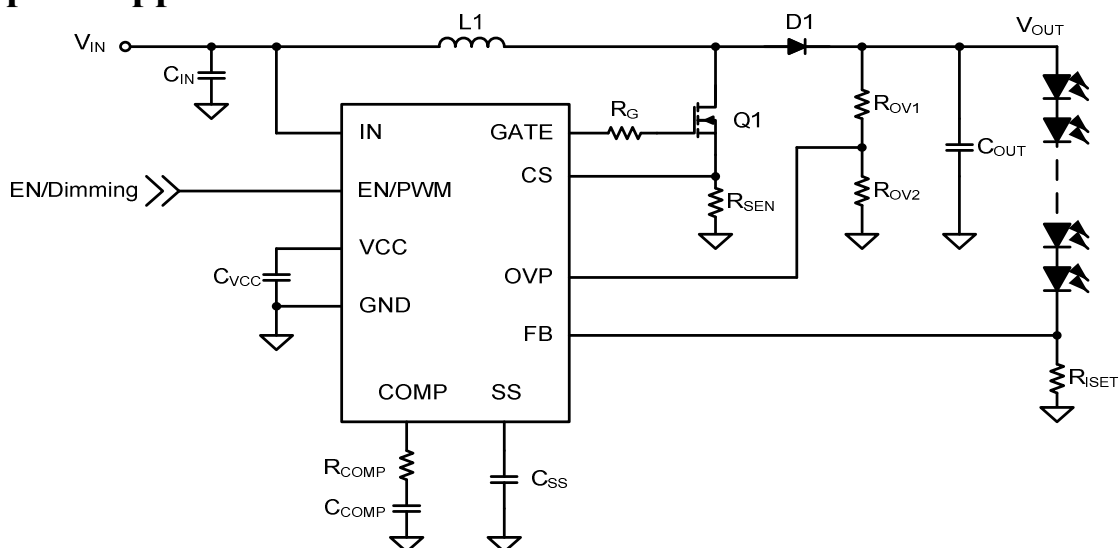
Features

- Input voltage range 3V to 25V
- 500kHz fixed switching frequency
- 100Hz~1kHz dimming frequency
- 10%~100% dimming duty cycle @200Hz dimming frequency
- External compensation
- Integrated low side driver: 1.5A sourcing and 3A sinking
- OVP, OTP functions
- RoHS Compliant and Halogen Free
- Compact package: DFN3x3-10, SOP10

Applications

- Monitor LCD Panel Backlight
- TV LCD Panel Backlight
- LED Lighting

Typical Applications

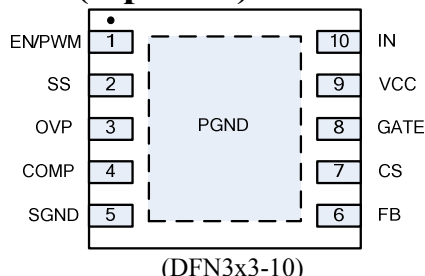


SY7701
Figure 1. Schematic Diagram

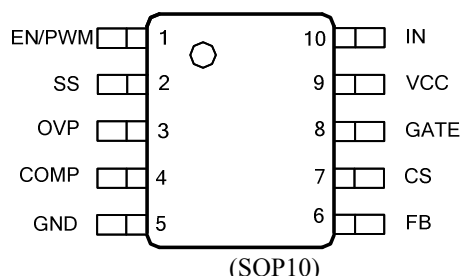


SY7701

Pinout (top view)



(DFN3x3-10)



(SOP10)

Top Mark: GOxyz for SY7701DBC (Device code:GO, x=year code, y=week code, z=lot number code)
AEY.xyz for SY7701FHC (Device code:AEY, x=year code, y=week code, z=lot number code)

Pin Name	Pin Number	Pin Description
IN	10	Input pin. Decouple this pin to GND pin with at least 1uF ceramic capacitor
VCC	9	5V Internal LDO output from VIN. Connect a 4.7 uF capacitor from this pin to GND
GATE	8	Driver pin. Connect to the gate of power MOSFET
CS	7	Current sense pin. Connect an external current sensing resistor R_S from this pin to GND. The voltage on this pin is used to provide mosfet current feedback in the control loop and cycle by cycle peak current limit. Peak current limit is triggered when the sensed voltage plus the slope compensation exceed 340mV
FB	6	Feedback pin. The LED current equals to: $I_{LED} = \frac{100mV}{R_{ISET}}$
GND	5(Exposed Paddle)	Ground pin
COMP	4	External compensation pin. Connect RC network from this pin to GND to compensate the control loop
OVP	3	Over Voltage Protection input pin. The OVP set point equals to : $V_{OVP} = \frac{1}{R_{OV2}} (R_{OV1} + R_{OV2})$
SS	2	Soft start pin. Connect a capacitor from this pin to GND to program the soft start time
EN/PWM	1	Enable and PWM dimming input pin. Pull it high to turn on the chip. Do not float this pin

Absolute Maximum Ratings (Note 1)

IN,	26V
GATE	VCC+0.3V
All other pins	6V
Power Dissipation, P_D @ $T_A = 25^\circ\text{C}$, DFN3x3-10, SOP10	2.6W/TBD
Package Thermal Resistance (Note 2)	
θ_{JA}	38°C/W/TBD
θ_{JC}	130°C/W/TBD
Junction Temperature Range	125°C
Lead Temperature (Soldering, 10 sec.)	260°C
Storage Temperature Range	-65°C to 150°C

Recommended Operating Conditions (Note 3)

IN	3V to 25V
Junction Temperature Range	-40°C to 125°C



Ambient Temperature Range ----- -40°C to 85°C

Electrical Characteristics(V_{IN} = 12V, T_A = 25°C, unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input Voltage Range	V _{IN}		3		25	V
Quiescent Current	I _Q	V _{OVP} =1.1V		170		uA
Shutdown Current	I _{SHDN}	EN=0		0.1		uA
OVP Threshold	V _{OVP}		0.98	1	1.02	V
FB Input Current	I _{FB}		-50		50	nA
Feedback Reference Voltage	V _{REF}		98	100	102	mV
Internal Slope Compensation	V _{SLOPE}			40		mV/uS
Gate Driver Output Peak Current	I _{SOURCE}			1.5		A
	I _{SINK}			3		A
EN Rising Threshold	V _{ENH}		1.5			V
EN Falling Threshold	V _{ENL}				0.4	V
Input UVLO threshold	V _{UVLO}				2.9	V
UVLO hysteresis	V _{HYS}			0.3		V
Oscillator Frequency	F _{OSC}			500		kHz
Min On Time				200		ns
Min Off Time				200		ns
Internal LDO Output	V _{VCC}	V _{IN} =5.5V	4.9	5	5.1	V
Thermal Shutdown	T _{SD}			150		°C
Thermal Hysteresis	T _{HYST}			20		°C

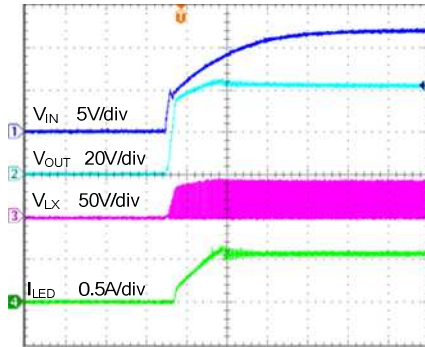
Note 1: Stresses beyond the “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 2: θ_{JA} is measured in the natural convection at T_A = 25°C on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard. Test condition: Device mounted on 2” x 2” FR-4 substrate PCB, 2oz copper, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane.

Note 3: The device is not guaranteed to function outside its operating conditions.

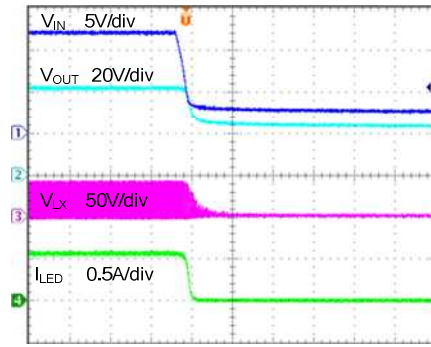
Typical Performance Characteristics

Startup from V_{IN}
($V_{IN}=12V$, 10 LED in series, $I_{LED}=560mA$)



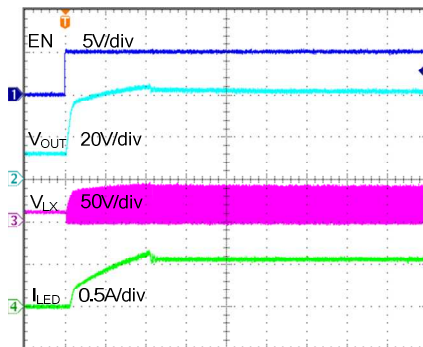
Time (2ms/div)

Shutdown from V_{IN}
($V_{IN}=12V$, 10 LED in series, $I_{LED}=560mA$)



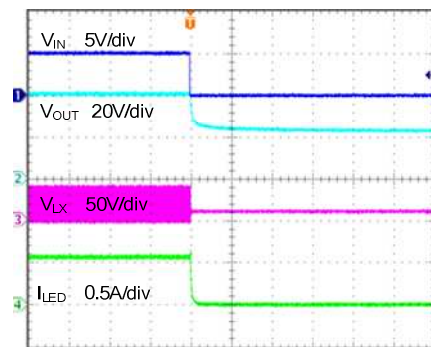
Time (2ms/div)

Startup from Enable
($V_{IN}=12V$, 10 LED in series, $I_{LED}=560mA$)



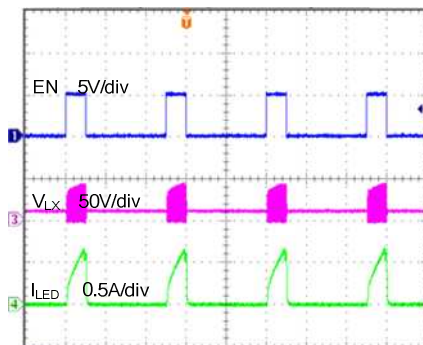
Time (1ms/div)

Shutdown from Enable
($V_{IN}=12V$, 10 LED in series, $I_{LED}=560mA$)



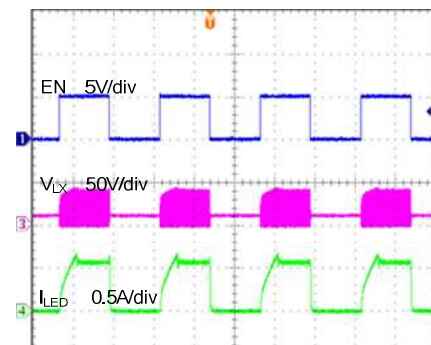
Time (1ms/div)

Dimming
($V_{IN}=12V$, 10 LED in series,
 $I_{LED}=560mA$, $f_{PWM}=100Hz$, Duty=20%)



Time (4ms/div)

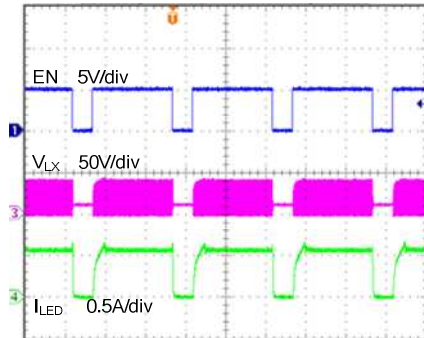
Dimming
($V_{IN}=12V$, 10 LED in series,
 $I_{LED}=560mA$, $f_{PWM}=100Hz$, Duty=50%)



Time (4ms/div)

Dimming

($V_{IN}=12V$, 10 LED in series,
 $I_{LED}=560mA$, $f_{PWM}=100Hz$, Duty=80%)



Time (4mS/div)



Operation

SY7701 is a boost controller targetted for white LED lighting. It integrates a low side driver which is capable of sourcing 1.5A and sinking 3A current. External compensation can supply a flexible adjustment of control loop under different applications. OVP function can protect the part from LED open event, OVP point can be programmed using a voltage divider.

Applications Information

LED current programming resistor R_{ISET}

LED current is programmed by a resistor which is in series with the LED string. LED current is calculated as: $I_{LED} = 100\text{mV}/R_{SET}$

OVP point programming divider R_{OV1} and R_{OV2}:

Choose proper resistor R_{OV1} and R_{OV2} to program the output voltage OVP point. V_{OVP} is calculated as: $V_{OVP} = 1\text{V} \cdot (1 + R_{OV1}/R_{OV2})$

Make sure the resistor will not exceed its power rating when output voltage reaches the OVP point.

Peak Current Sense Resistor

An external sensing resistor R_{SEN} is used to sense the current flow through the MOSFET. The sensed voltage is for peak current mode control and cycle by cycle peak current limit. Peak current limit will be triggered when the voltage on CS pin plus the internal slope compensation exceed 340mV, which is the typical clamping voltage of the PWM comparator. It is desirable to make the maximum value of sensing voltage plus the slope compensation to be about 70% of the clamping voltage during normal operation. Thus,

$$R_S = \frac{70\% \times 0.34\text{-Vslope} \times D \times T_s}{I_{PEAK}}$$

V_{slope} is the slew rate of the internal compensation, I_{PEAK} is the peak current through MOSFET.

Inductor L:

There are several considerations in choosing this inductor.

1) Choose the inductance to provide the desired ripple current. It is suggested to choose the ripple

current to be about 40% of the maximum average input current. The inductance is calculated as:

$$L = \left(\frac{V_{IN}}{V_{OUT}} \right)^2 \frac{(V_{OUT} - V_{IN})}{F_{SW} \times I_{OUT,MAX} \times 40\%}$$

where F_{SW} is the switching frequency and I_{OUT,MAX} is the maximum load current.

The SY7701 regulator IC is quite tolerant of different ripple current amplitude. Consequently, the final choice of inductance can be slightly off the calculation value without significantly impacting the performance.

2) The saturation current rating of the inductor must be selected to be greater than the peak inductor current under full load conditions.

$$I_{SAT,MIN} > \left(\frac{V_{OUT}}{V_{IN}} \right) \times I_{OUT,MAX} + \frac{V_{IN}(V_{OUT} - V_{IN})}{2 \times F_{SW} \times L \times V_{OUT}}$$

3) The DCR of the inductor and the core loss at the switching frequency must be low enough to achieve the desired efficiency requirement. It is desirable to choose an inductor with DCR < 50mohm to achieve a good overall efficiency.

Input capacitor C_{IN}:

The ripple current through input capacitor is calculated as:

$$I_{CIN,RMS} = \frac{V_{IN} \cdot (V_{OUT} - V_{IN})}{2\sqrt{3} \cdot L \cdot F_{SW} \cdot V_{OUT}}$$

To minimize the potential noise problem, place a typical X7R or better grade ceramic capacitor really close to the IN and GND pins. Care should be taken to minimize the loop area formed by C_{IN}, and IN/GND pins.

Output capacitor C_{OUT}:

The output capacitor is selected to handle the output ripple noise requirements. Both steady state ripple and transient requirements must be taken into consideration when selecting this capacitor. Voltage rating of the capacitor should be carefully selected to at least over the programmed OVP point.

Layout Design:

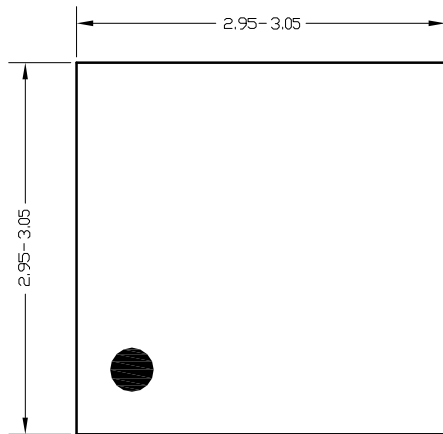
To minimize noise problem, attention should be paid to the PCB layout.



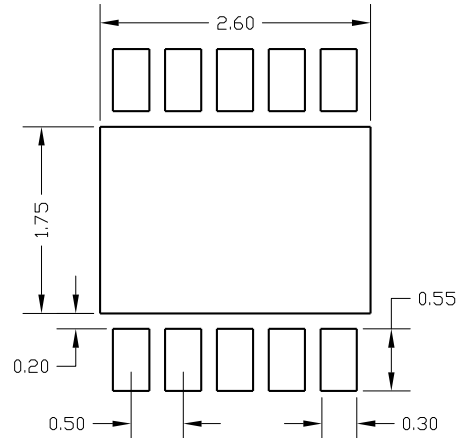
SY7701

- 1) The internal LDO output capacitor C_{VCC} should be put as close as possible to the VCC pin and GND pin.
- 2) The input capacitor C_{IN} should be put as close as possible to the IN pin and GND pin.
- 3) The loop formed by inductor L1, Power MOS Q1, output capacitor C_{OUT} and power GND should be small enough to suppress voltage spike on Power MOS when it is turned off.
- 4) Current sense signal generated by R_{SEN} should return to CS PIN as short as possible.
- 5) Gate drive wire from GATE pin to gate terminal of the Power MOS should be short enough to avoid drive problem.

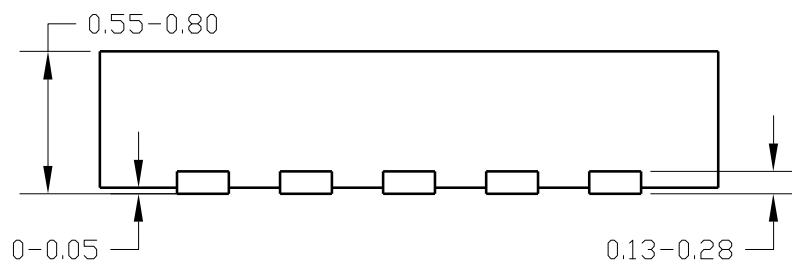
DFN3x3-10 Package outline



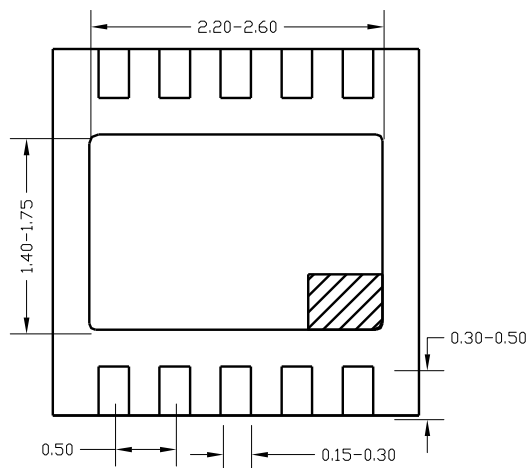
Top View



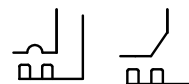
PCB layout (recommended)



Side View



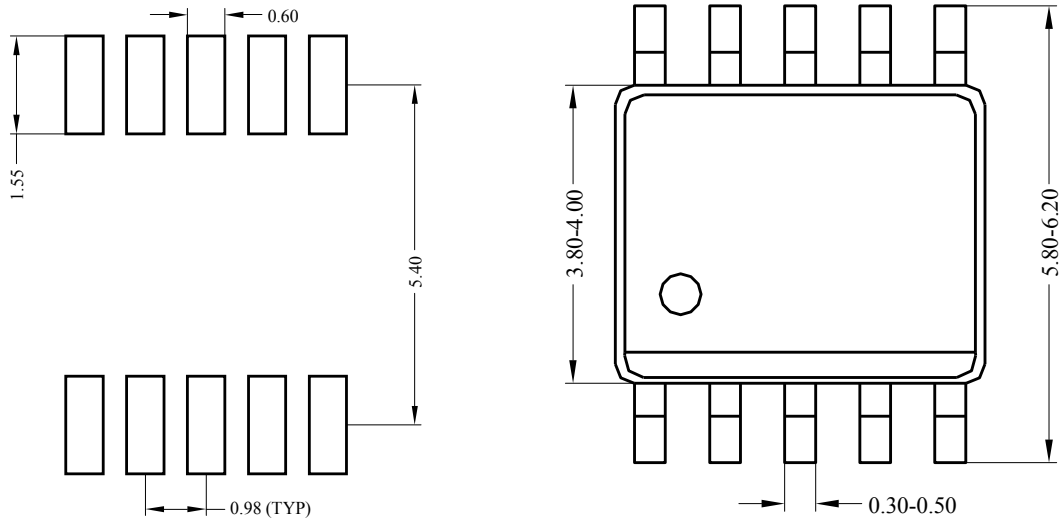
Bottom View



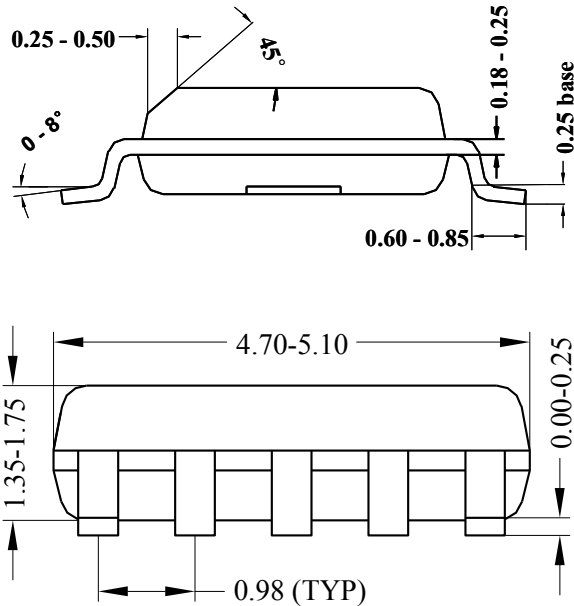
Detail A
Pin1 identifier: two options

Notes: All dimensions are in millimeters and exclude mold flash & metal burr.

SO10 Package outline & PCB layout design



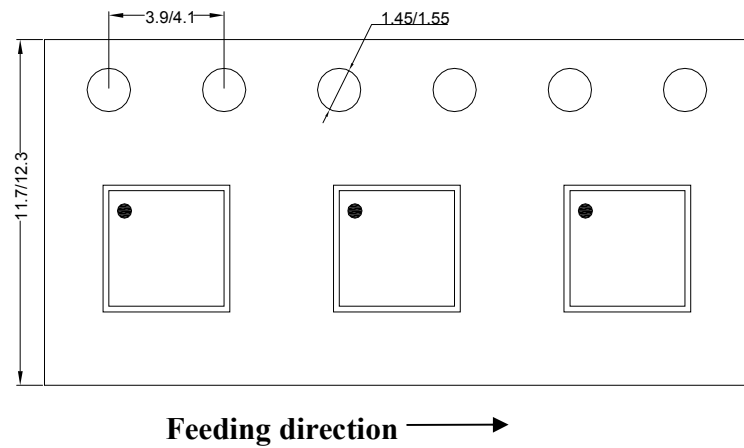
Recommended Pad Layout



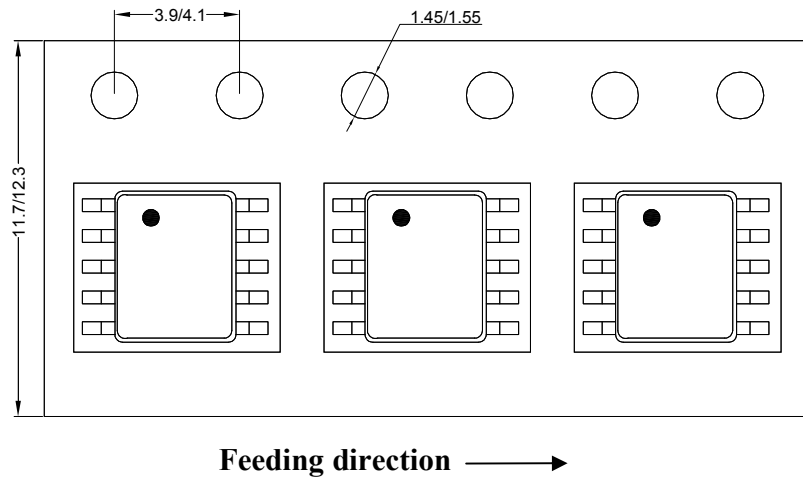
Notes: All dimension in MM
 All dimension don't not include mold flash & metal burr

Taping & Reel Specification

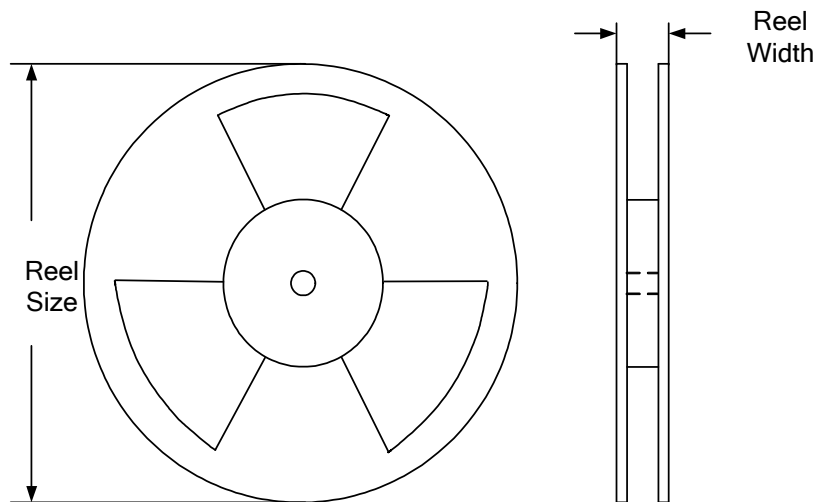
1. DFN3x3-10 taping orientation



SOP10 taping orientation



2. Carrier Tape & Reel specification for packages



Package types	Tape width (mm)	Pocket pitch(mm)	Reel size (Inch)	Reel width(mm)	Trailer length(mm)	Leader length (mm)	Qty per reel
DFN3x3	12	8	13"	12.4	400	400	5000
SO10	12	8	13"	12.4	400	400	2500